

Notice of References Cited				Application No. 09/319,699		Applicant(s) Lippert et al.	
				Examiner Douglas Wille		Group Art Unit 2814	

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*	DOCUMENT NO.	DATE	NAME	CLASS	SUBCLASS	
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* A copy of this reference is not being furnished with this Office action.
(See Manual of Patent Examining Procedure, Section 707.05(a).)